

**MCH3317**

Ultrahigh-Speed Switching Applications

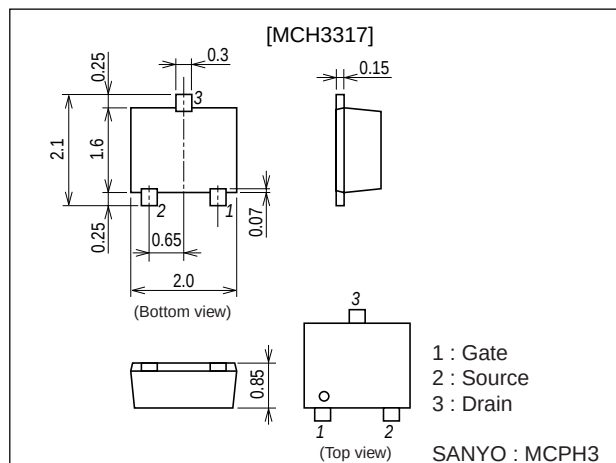
Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 1.8V drive.

Package Dimensions

unit : mm

2167A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DS}		-12	V
Gate-to-Source Voltage	V_{GS}		±10	V
Drain Current (DC)	I_D		-1.5	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	-6	A
Allowable Power Dissipation	P_D	Mounted on a ceramic board (900mm ² ×0.8mm)	0.8	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1mA$, $V_{GS} = 0$	-12			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -12V$, $V_{GS} = 0$			-10	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 8V$, $V_{DS} = 0$			±10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -6V$, $I_D = -1mA$	-0.3		-1.0	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -6V$, $I_D = -0.8A$	1.3	1.8		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = -0.8A$, $V_{GS} = -4.5V$		220	290	mΩ
	$R_{DS(on)2}$	$I_D = -0.4A$, $V_{GS} = -2.5V$		320	450	mΩ
	$R_{DS(on)3}$	$I_D = -0.1A$, $V_{GS} = -1.8V$		430	650	mΩ

Marking : JS

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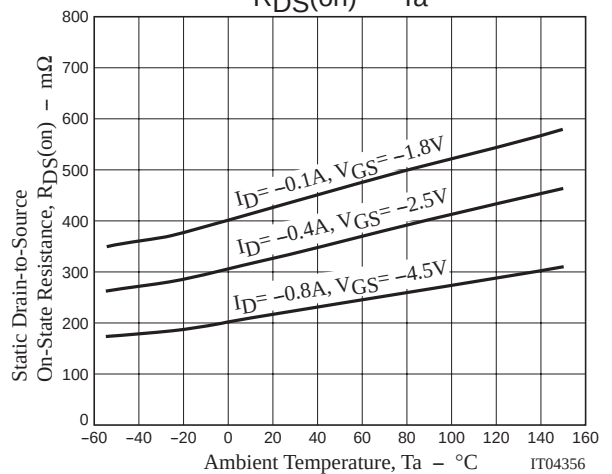
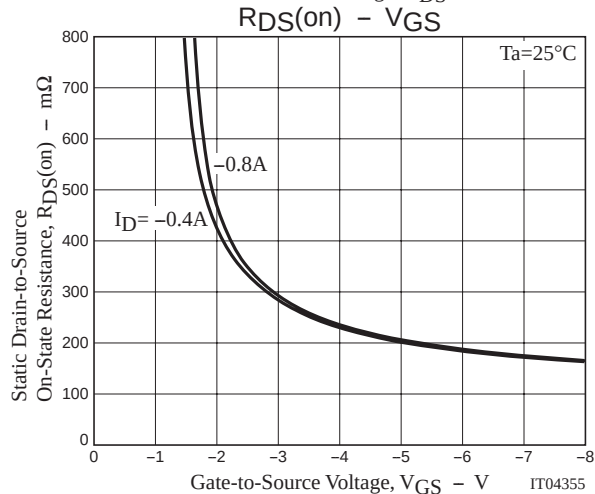
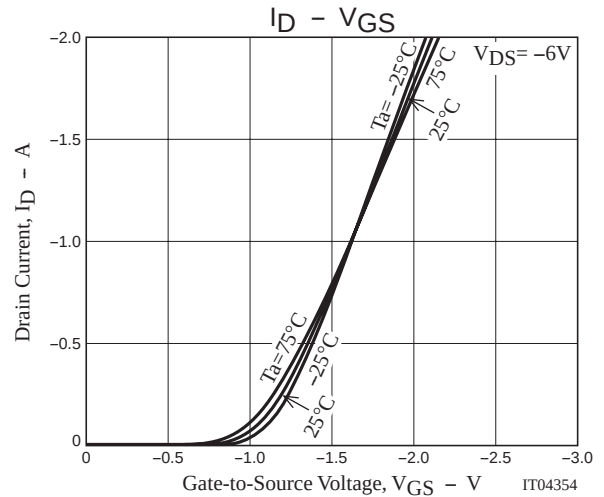
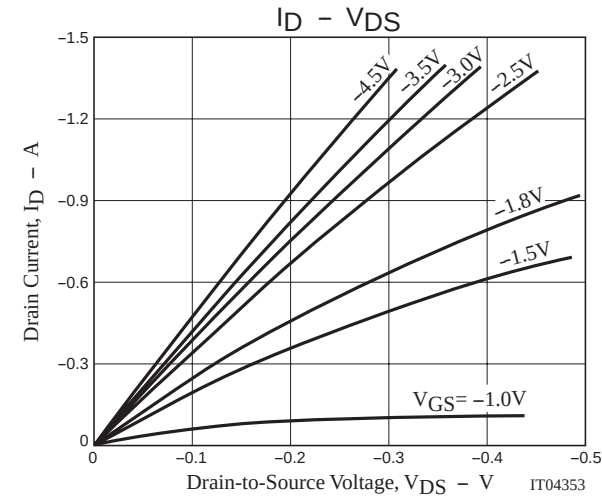
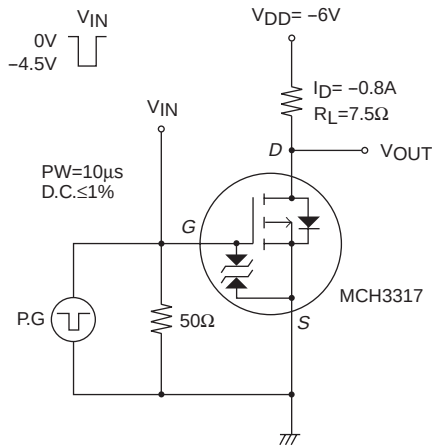
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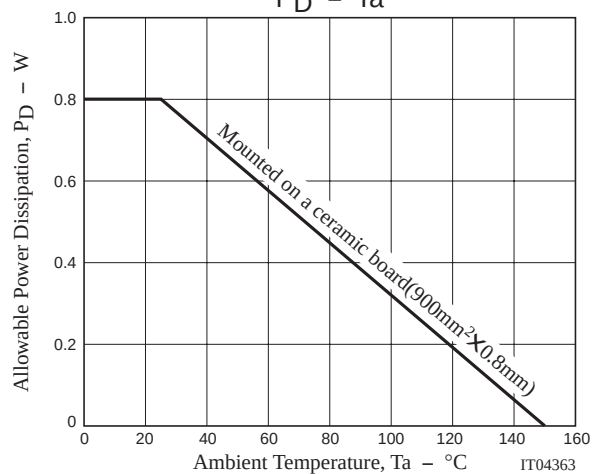
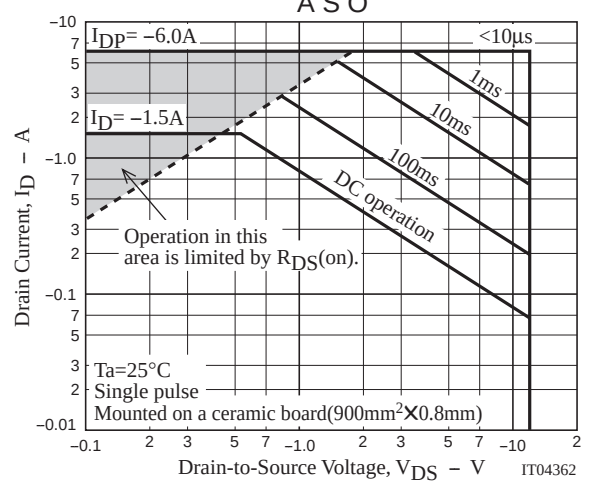
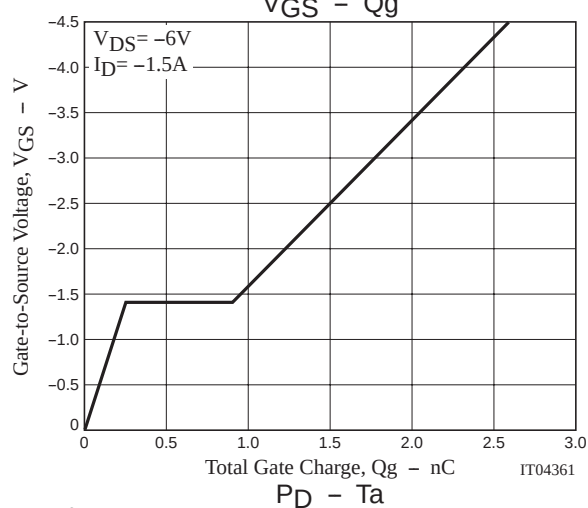
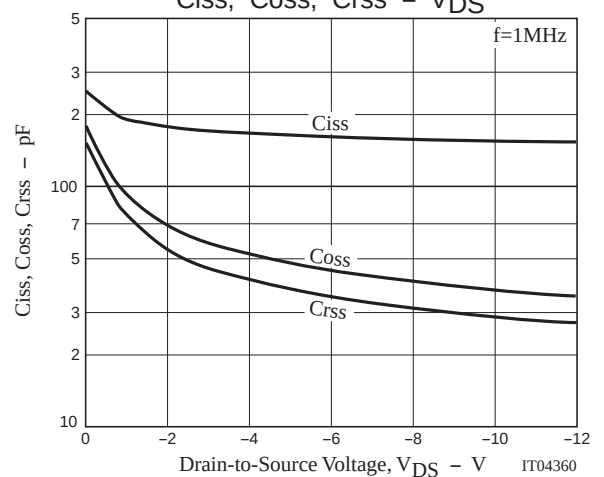
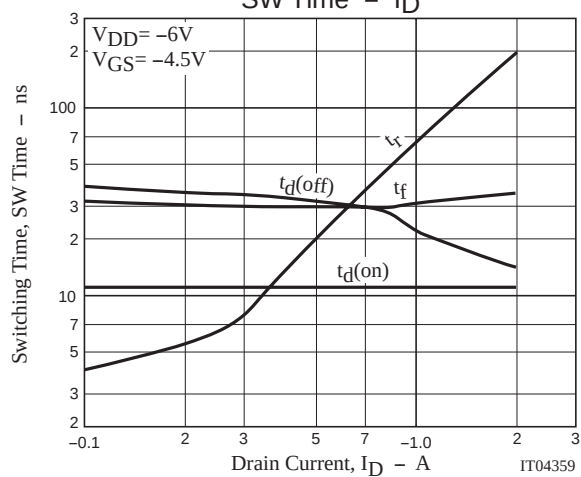
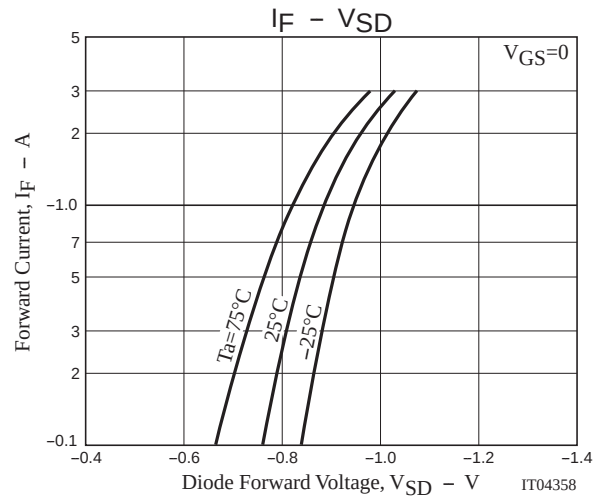
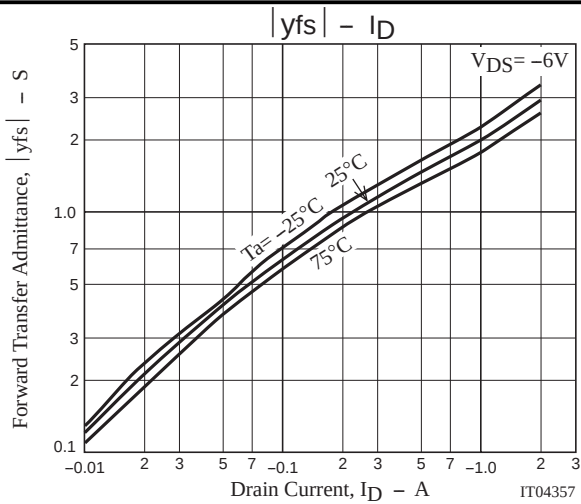
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	C_{iss}	$V_{DS} = -6V, f = 1MHz$		160		pF
Output Capacitance	C_{oss}	$V_{DS} = -6V, f = 1MHz$		45		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = -6V, f = 1MHz$		35		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		11		ns
Rise Time	t_r	See specified Test Circuit.		45		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		29		ns
Fall Time	t_f	See specified Test Circuit.		30		ns
Total Gate Charge	Q_g	$V_{DS} = -6V, V_{GS} = -4.5V, I_D = -1.5A$		2.6		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS} = -6V, V_{GS} = -4.5V, I_D = -1.5A$		0.25		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS} = -6V, V_{GS} = -4.5V, I_D = -1.5A$		0.65		nC
Diode Forward Voltage	V_{SD}	$I_S = -1.5A, V_{GS} = 0$		-0.92	-1.5	V

Switching Time Test Circuit





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